2SD1271A

Silicon NPN epitaxial planar type

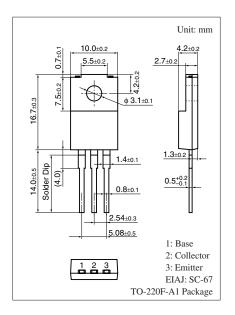
For power switching

■ Features

- ullet Low collector-emitter saturation voltage $V_{\text{CE(sat)}}$
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Large collector current I_C
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter	V_{CBO}	150	V	
Collector-emitter voltage (Base	V _{CEO}	100	V	
Emitter-base voltage (Collector open)		V _{EBO}	7	V
Collector current		I_C	7	A
Peak collector current	I_{CP}	15	A	
Collector power		P _C	40	W
dissipation $T_a =$	25°C		2.0	
Junction temperature		T_{j}	150	°C
Storage temperature		T _{stg}	-55 to +150	°C



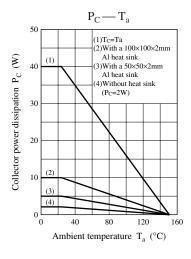
■ Electrical Characteristics $T_C = 25$ °C ± 3 °C

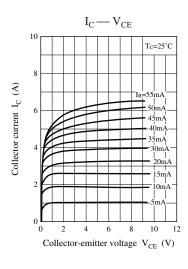
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 10 \text{ mA}, I_B = 0$	100			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 100 \text{ V}, I_E = 0$			10	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 5 \text{ V}, I_{C} = 0$			50	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CE} = 2 \text{ V}, I_{C} = 0.1 \text{ A}$	45			_
	h _{FE2} *	$V_{CE} = 2 \text{ V}, I_{C} = 3 \text{ A}$	60		260	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 5 \text{ A}, I_B = 0.25 \text{ A}$			0.5	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_C = 5 \text{ A}, I_B = 0.25 \text{ A}$			1.5	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.5 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t _{on}	$I_C = 1 A$, $I_{B1} = 0.1 A$, $I_{B2} = -0.1 A$		0.5		μs
Storage time	t _{stg}	$V_{CC} = 50 \text{ V}$		2.5		μs
Fall time	t _f			0.4		μs

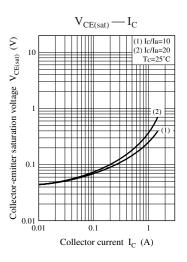
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

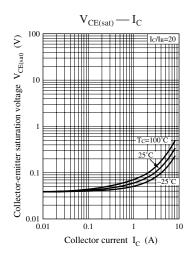
2. *: Rank classification

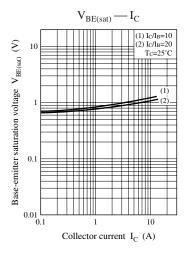
Rank	R	Q	Р	
h _{FE2}	60 to 120	90 to 180	130 to 260	

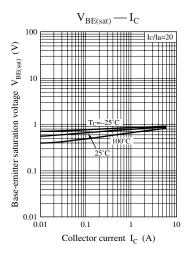


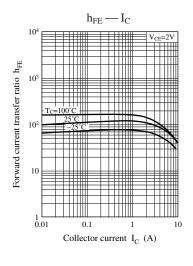


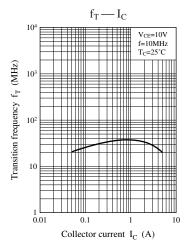


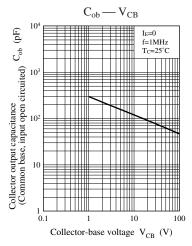


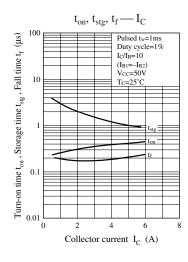


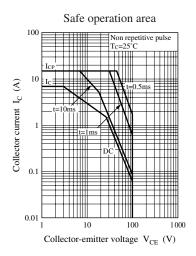


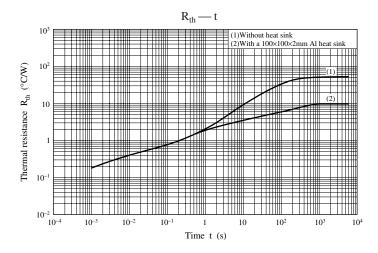












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